

## Features

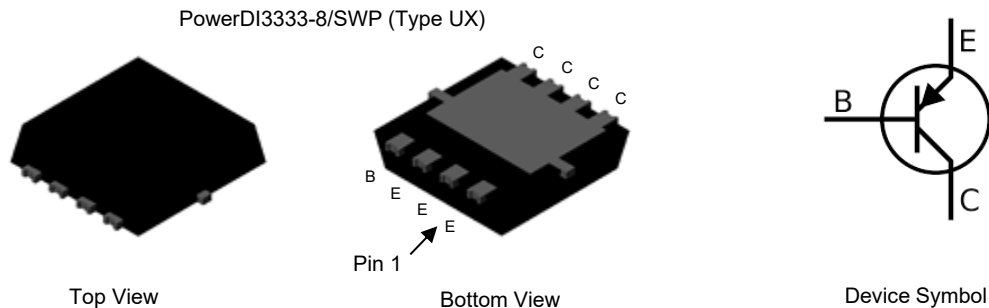
- $BV_{CE0} > -30V$
- $BV_{EBO} > -8V$
- Continuous Current  $I_C$  to  $-6.5A$
- Peak Pulse Current  $I_{CM}$  to  $-12A$
- Ultra-Low Saturation Voltage  $V_{CE(sat)} < -40mV @ -1A$
- High Current  $R_{CE(sat)} = 16m\Omega$  Typical
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Wettable Flank for Improved Optical Inspection
- Rated to  $+175^\circ C$  – Ideal for High-Temperature Environments
- Complementary NPN Type: [DXTN78030DFGQ](#)
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DXTP78030DFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**  
<https://www.diodes.com/quality/product-definitions/>

## Mechanical Data

- Package: PowerDI<sup>®</sup>3333-8
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin. Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.03 grams (Approximate)

## Applications

- MOSFET & IGBT gate drivers
- Load switches
- Low-voltage regulation
- DC to DC converters
- Motors, solenoids, relays and actuator drivers control



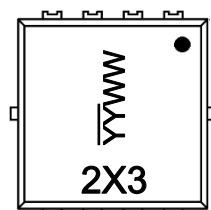
## Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
DXTP78030DFGQ-7	PowerDI3333-8/SWP (Type UX)	2X3	7	12	2,000	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information

PowerDI3333-8/SWP (Type UX)



2X3 = Product Type Marking Code  
 YYWW = Date Code Marking  
 YY = Last Two Digits of Year (ex: 25 = 2025)  
 WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated in the United States and other countries.

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB0</sub>	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-30	V
Emitter-Base Voltage	V <sub>EBO</sub>	-8	V
Continuous Collector Current (Note 5)	I <sub>C</sub>	-3	A
Continuous Collector Current (Note 7)	I <sub>C</sub>	-6.5	A
Peak Pulse Current	I <sub>CM</sub>	-12	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

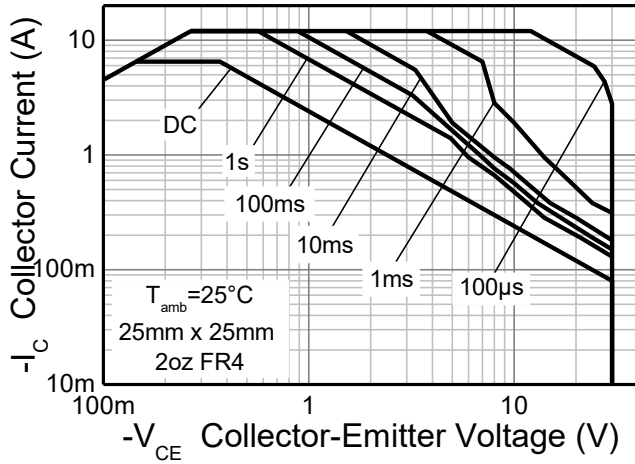
Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	900	mW
		1.6	W
		2.4	W
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	140	°C/W
		92	°C/W
		62.5	°C/W
Thermal Resistance, Junction to Case (Note 7)	R <sub>θJC</sub>	8	°C/W
Thermal Resistance, Junction to Lead (Note 8)	R <sub>θJL</sub>	6.5	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C

**ESD Ratings** (Note 9)

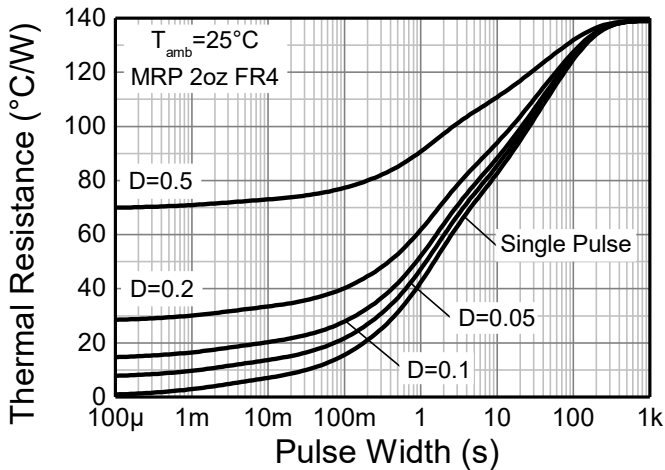
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C
Electrostatic Discharge - Charged Device Model	ESD CDM	1,000	V	IV

- Notes:
5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady state.
  6. Same as Note 5, except the device is mounted on 15mm x 15mm 2oz copper.
  7. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
  8. Thermal resistance from junction to solder-point (at the collector tab).
  9. Refer to JEDEC specifications JESD22-A114, JESD22-A115 and JESD22-C101.

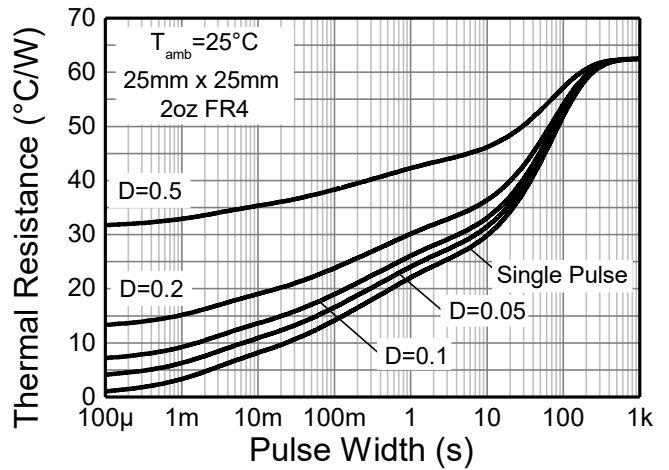
**Thermal Characteristics and Derating Information**



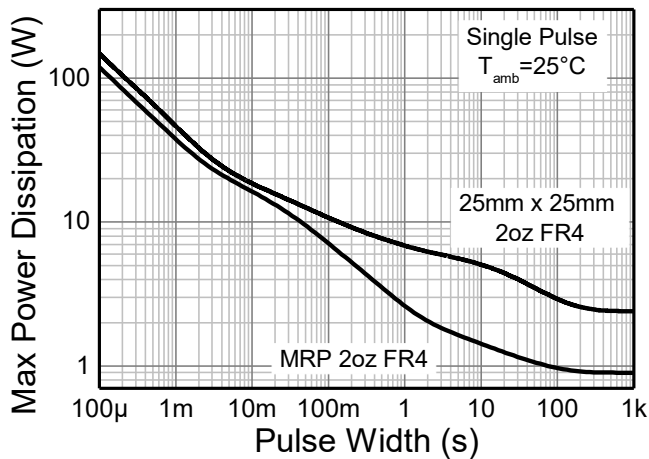
**Fig 1. Safe Operating Area**



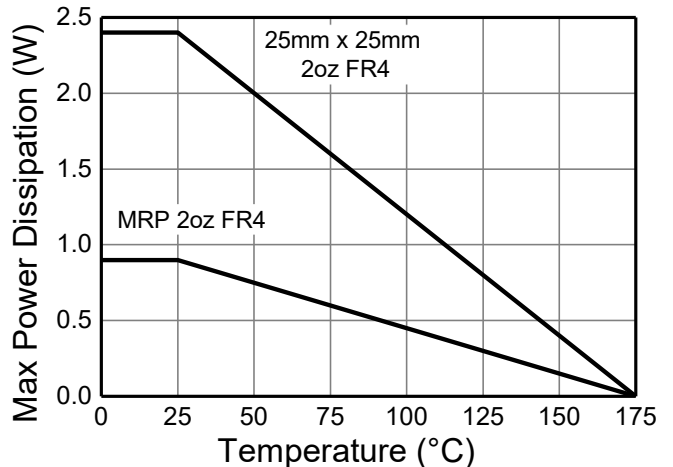
**Fig 2. Transient Thermal Impedance**



**Fig 3. Transient Thermal Impedance**



**Fig 4. Pulse Power Dissipation**

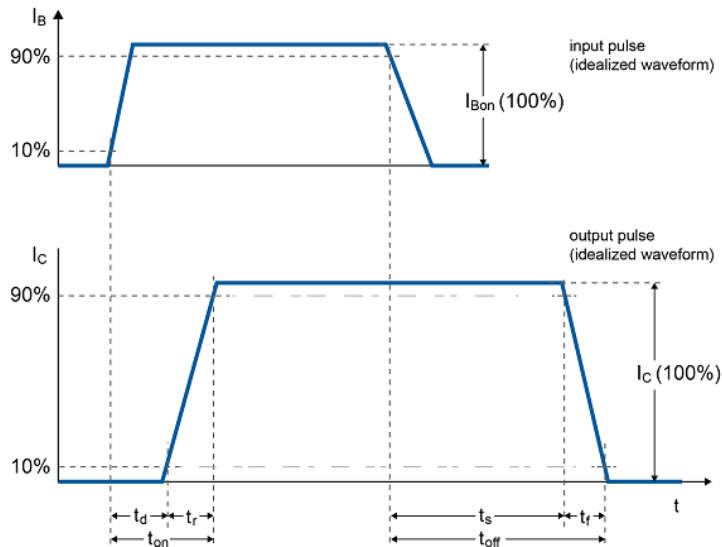


**Fig 5. Derating Curve**

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

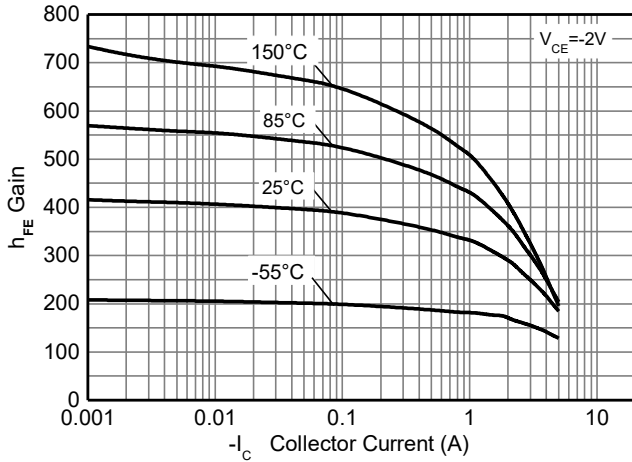
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CB0</sub>	-40	—	—	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	-30	—	—	V	I <sub>C</sub> = -10mA
Emitter-Collector Breakdown Voltage	BV <sub>ECO</sub>	-5	—	—	V	I <sub>E</sub> = -100μA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-8	—	—	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>	—	—	-100	nA	V <sub>CB</sub> = -30V
		—	—	-10	μA	V <sub>CB</sub> = -30V, T <sub>A</sub> = +125°C
Collector Cutoff Current	I <sub>CES</sub>	—	—	-300	nA	V <sub>CE</sub> = -24V
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	-50	nA	V <sub>EB</sub> = -7V
Collector-Emitter Saturation Voltage (Note 10)	V <sub>CE(sat)</sub>	—	-40	—	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -1mA
		—	-50	-70	mV	I <sub>C</sub> = -1A, I <sub>B</sub> = -20mA
		—	-25	-40	mV	I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
		—	-140	-170	mV	I <sub>C</sub> = -3A, I <sub>B</sub> = -60mA
		—	-170	-250	mV	I <sub>C</sub> = -6.5A, I <sub>B</sub> = -325mA
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(sat)</sub>	—	-830	-950	mV	I <sub>C</sub> = -3A, I <sub>B</sub> = -80mA
		—	-940	-1,100	mV	I <sub>C</sub> = -6.5A, I <sub>B</sub> = -375mA
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(on)</sub>	—	-760	-900	mV	I <sub>C</sub> = -3A, V <sub>CE</sub> = -2V
		—	-800	-900	mV	I <sub>C</sub> = -6.5A, V <sub>CE</sub> = -2V
DC Current Gain (Note 10)	h <sub>FE</sub>	250	440	—	—	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -2V
		300	430	550	—	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -2V
		220	355	—	—	I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V
		175	275	—	—	I <sub>C</sub> = -2A, V <sub>CE</sub> = -2V
		150	235	—	—	I <sub>C</sub> = -3A, V <sub>CE</sub> = -2V
		90	135	—	—	I <sub>C</sub> = -6.5A, V <sub>CE</sub> = -2V
Input Capacitance	C <sub>ibo</sub>	—	305	—	pF	V <sub>EB</sub> = 0.5V, f = 1MHz
Output Capacitance	C <sub>obo</sub>	—	24	—	pF	V <sub>CB</sub> = 10V, f = 1MHz
Current Gain-Bandwidth Product	f <sub>T</sub>	200	315	—	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -100mA f = 50MHz
Turn-On Time	t <sub>d</sub>	—	11.5	—	ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -3A I <sub>B1</sub> = -I <sub>B2</sub> = -300mA
	t <sub>r</sub>	—	35	—	ns	
Turn-Off Time	t <sub>s</sub>	—	120	—	ns	
	t <sub>f</sub>	—	6.5	—	ns	

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

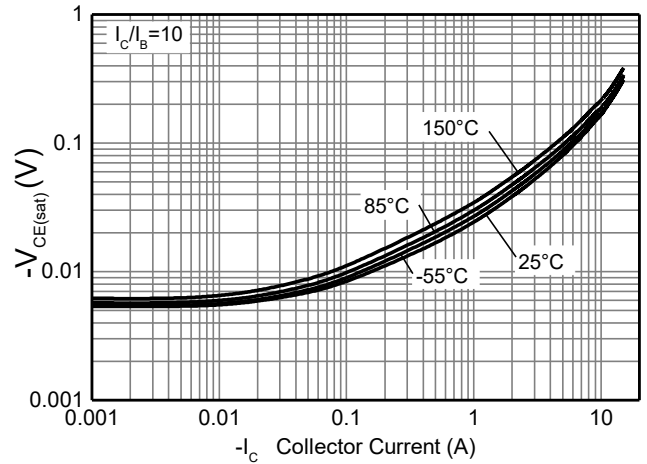


**Fig 6. Timing Waveform**

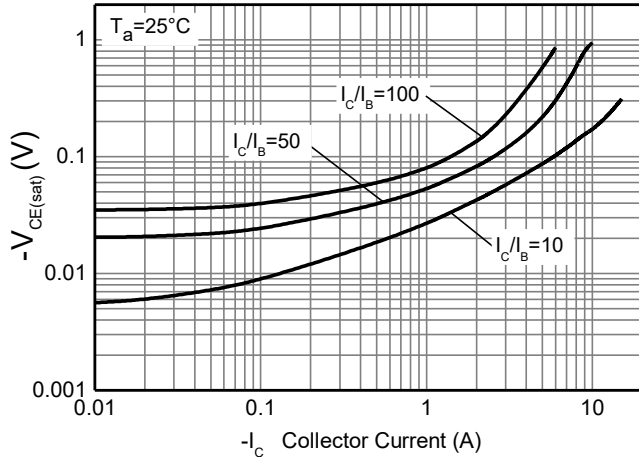
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



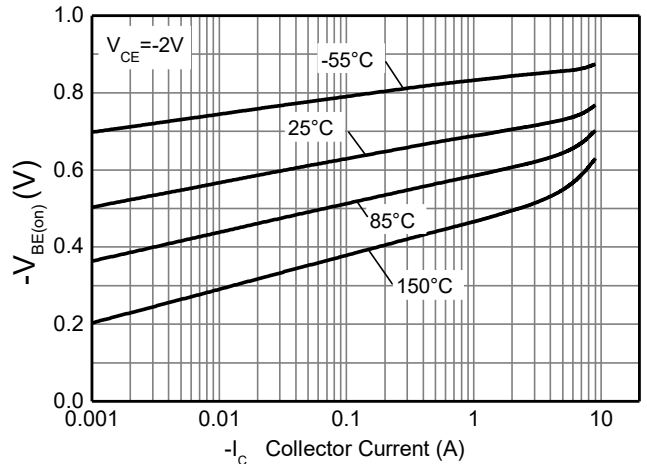
**Fig. 7**  $h_{FE} \ v \ I_C$



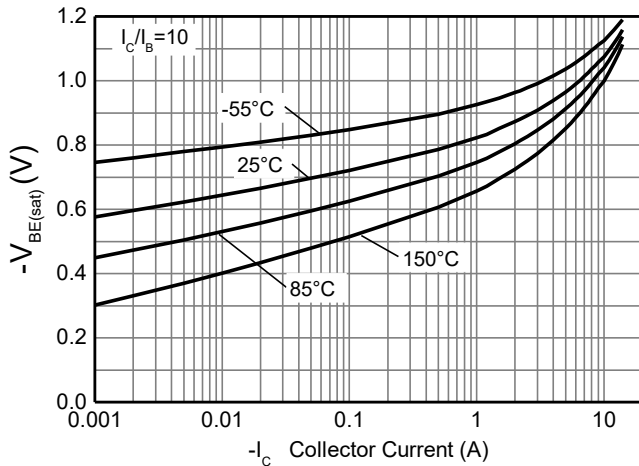
**Fig. 8**  $V_{CE(sat)} \ v \ I_C$



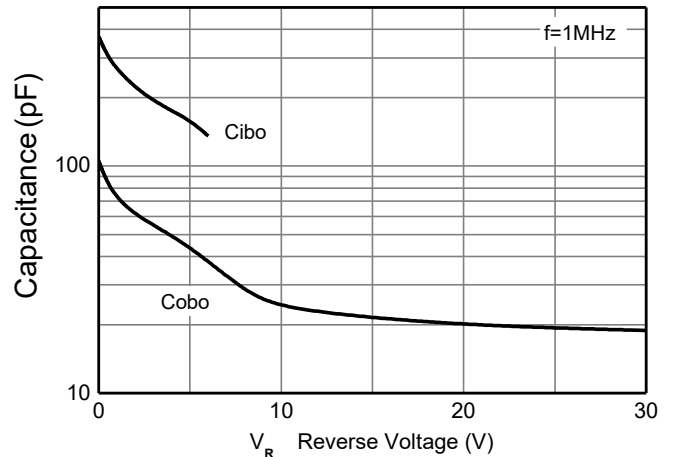
**Fig. 9**  $V_{CE(sat)} \ v \ I_C$



**Fig. 10**  $V_{BE(on)} \ v \ I_C$

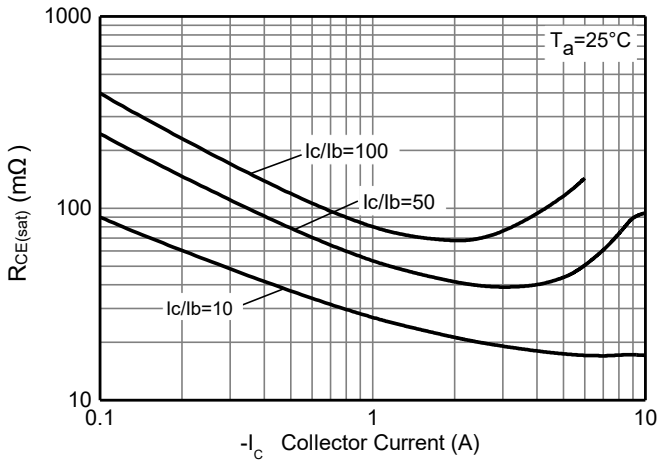


**Fig. 11**  $V_{BE(sat)} \ v \ I_C$

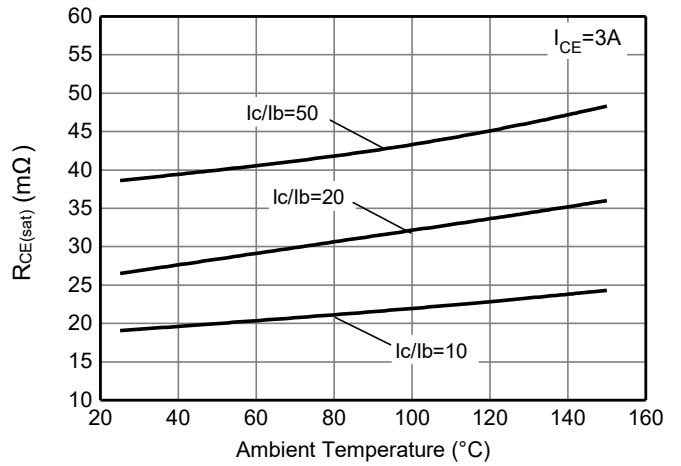


**Fig. 12** Typical Junction Capacitance

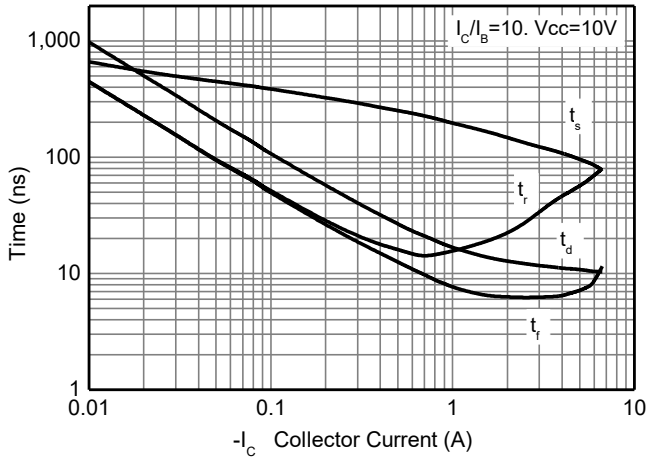
**Typical Electrical Characteristics** (continued) (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



**Fig. 13**  $R_{CE(sat)} \text{ v } I_C$



**Fig. 14**  $R_{CE(sat)} \text{ v } T_{amb}$

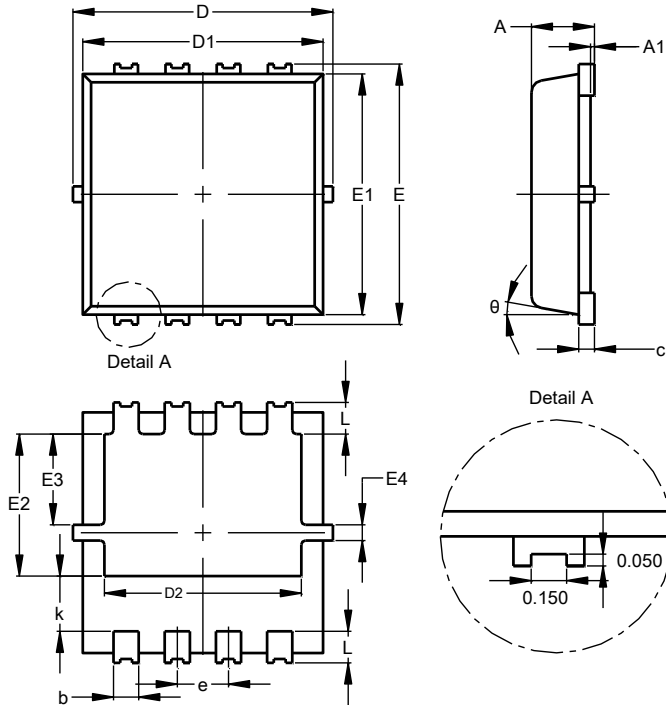


**Fig. 15** Switching Performance

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**PowerDI3333-8/SWP (Type UX)**

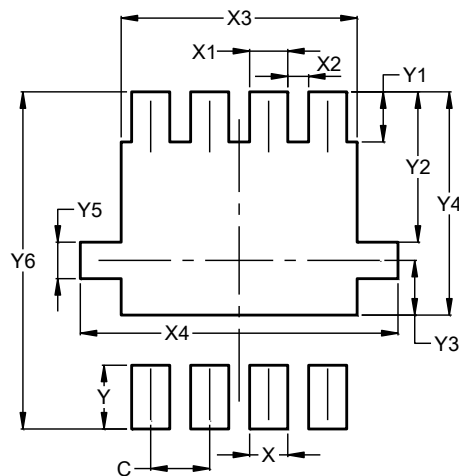


PowerDI3333-8/SWP (Type UX)			
Dim	Min	Max	Typ
A	0.75	0.85	0.80
A1	0.00	0.05	--
b	0.25	0.40	0.32
c	0.10	0.25	0.15
D	3.20	3.40	3.30
D1	2.95	3.15	3.05
D2	2.30	2.70	2.50
E	3.20	3.40	3.30
E1	2.95	3.15	3.05
E2	1.60	2.00	1.80
E3	0.95	1.35	1.15
E4	0.10	0.30	0.20
e	--	--	0.65
k	0.50	0.90	0.70
L	0.30	0.50	0.40
θ	0°	12°	10°
<b>All Dimensions in mm</b>			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**PowerDI3333-8/SWP (Type UX)**



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	0.420
X2	0.230
X3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: 11. Side wall tin plated package for wettable flanks in AOI.

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